

Low Vcesat NPN Epitaxial Planar Transistor

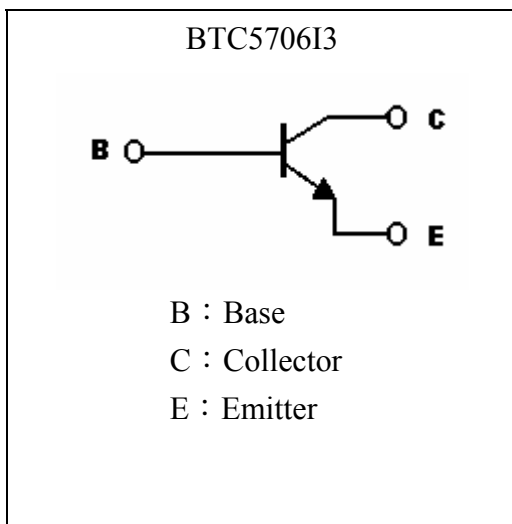
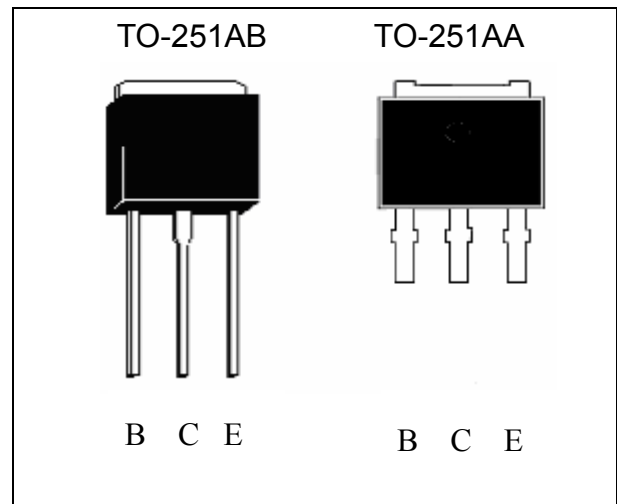
BTC5706I3

Features

- Low collector-to-emitter saturation voltage
- High-speed switching
- High allowable power dissipation
- Large current capability
- RoHS compliant package

Applications

- DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes.

Symbol**Outline**



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CES}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current (DC)	I _C	5	A
Collector Current (Pulse)	I _{CP}	7.5 (Note 1)	
Base Current	I _B	1.2	A
Power Dissipation @ T _A =25°C	P _D	0.8	W
Power Dissipation @ T _C =25°C	P _D	15	
Thermal Resistance, Junction to Ambient	R _{θJA}	156	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	8.33	°C/W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55~+150	°C

Note : 1. Single Pulse , Pw ≤ 380μs, Duty ≤ 2%.

Characteristics (Ta=25°C)

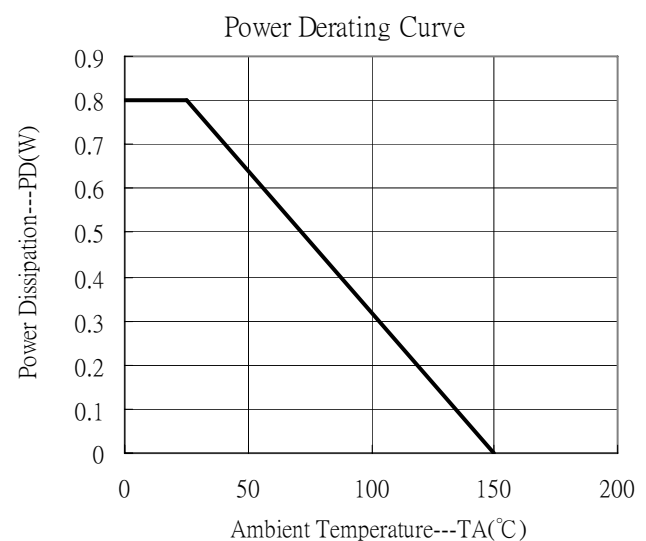
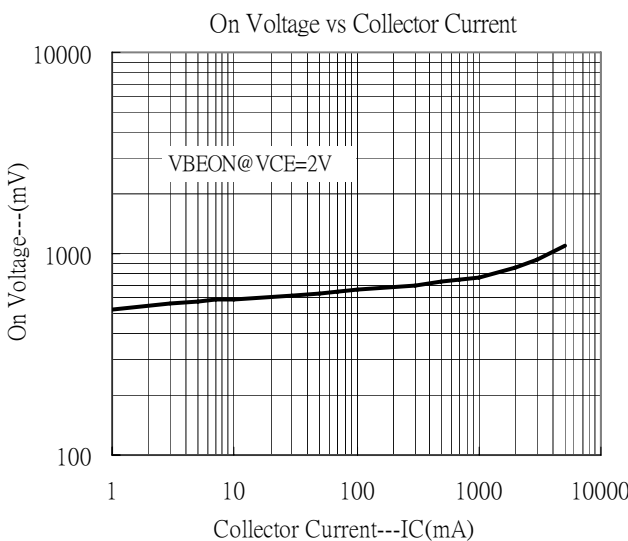
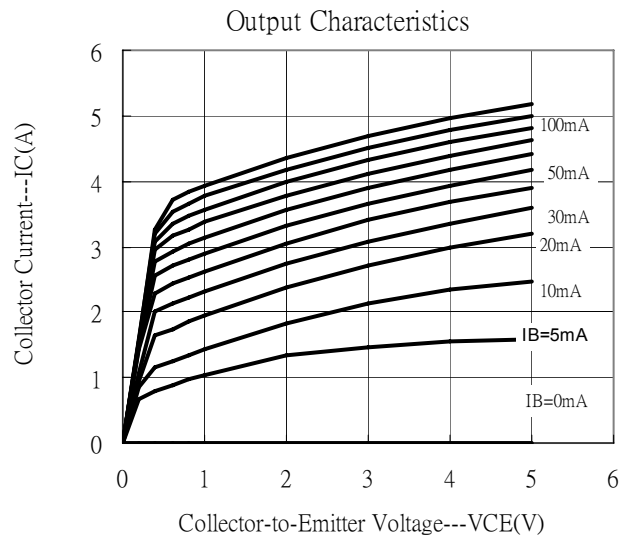
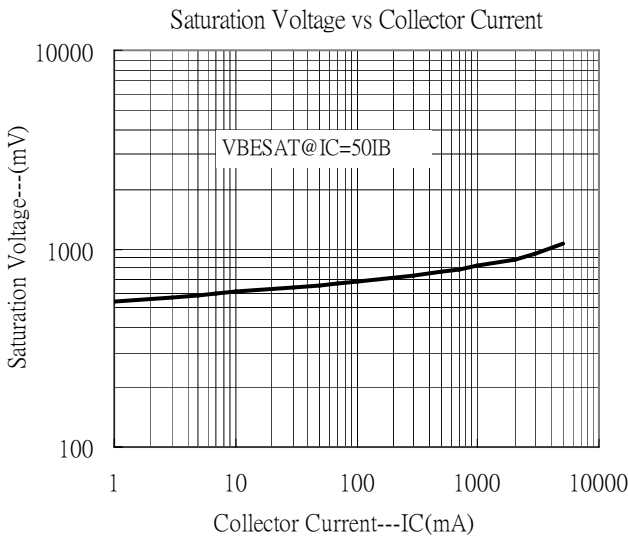
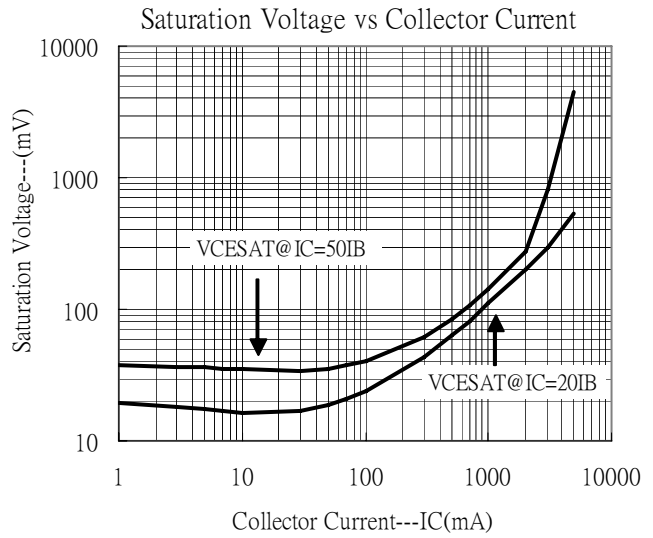
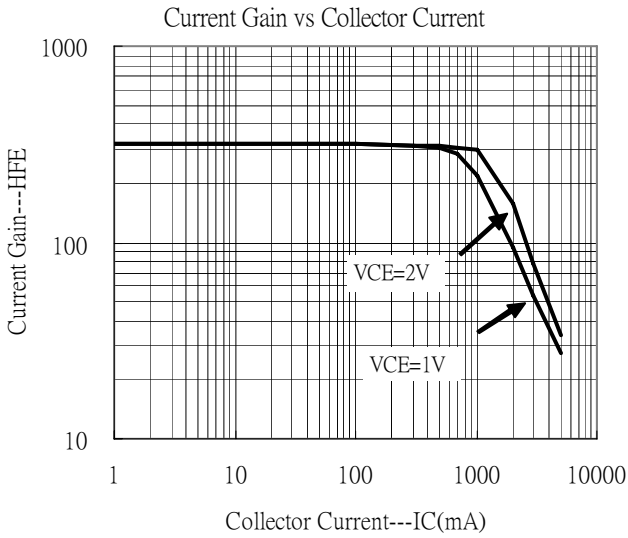
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	80	-	-	V	I _C =10μA, I _E =0
BV _{CES}	80	-	-	V	I _C =100μA, R _{BE} =0
*BV _{CEO}	60	-	-	V	I _C =1mA, I _B =0
BV _{EBO}	6	-	-	V	I _C =10μA, I _C =0
I _{CBO}	-	-	1	μA	V _{CB} =80V, I _E =0
I _{EBO}	-	-	1	μA	V _{EB} =4V, I _C =0
*V _{CE(sat)} 1	-	110	135	mV	I _C =1A, I _B =50mA
*V _{CE(sat)} 2	-	200	240	mV	I _C =2A, I _B =100mA
*V _{BE(sat)}	-	0.89	1.2	V	I _C =2A, I _B =100mA
*h _{FE}	200	-	560	-	V _{CE} =2V, I _C =500mA
f _T	-	400	-	MHz	V _{CE} =10V, I _C =500mA
Cob	-	15	-	pF	V _{CB} =10V, f=1MHz
t _{on}	-	35	-	ns	V _{CC} =25V, I _C =10I _{B1} =-10I _{B2} =1A, R _L =25Ω
t _{stg}	-	300	-	ns	
t _f	-	20	-	ns	

*Pulse Test : Pulse Width ≤ 380μs, Duty Cycles ≤ 2%

Ordering Information

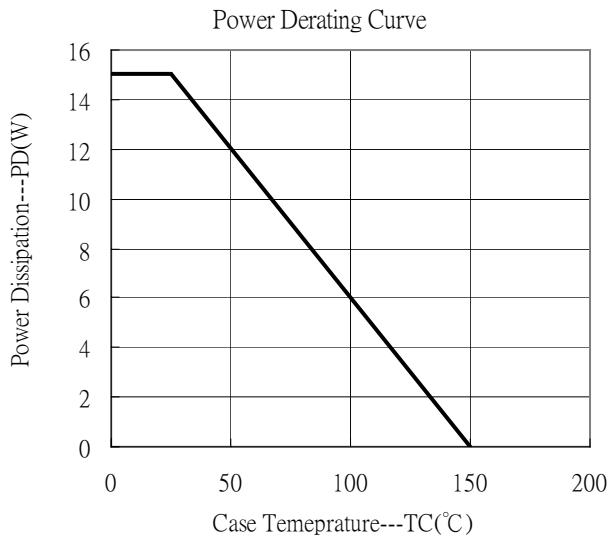
Device	Package	Shipping	Marking
BTC5706I3	TO-251 (RoHS compliant)	80 pcs / tube, 50 tubes / box	C5706

Characteristic Curves



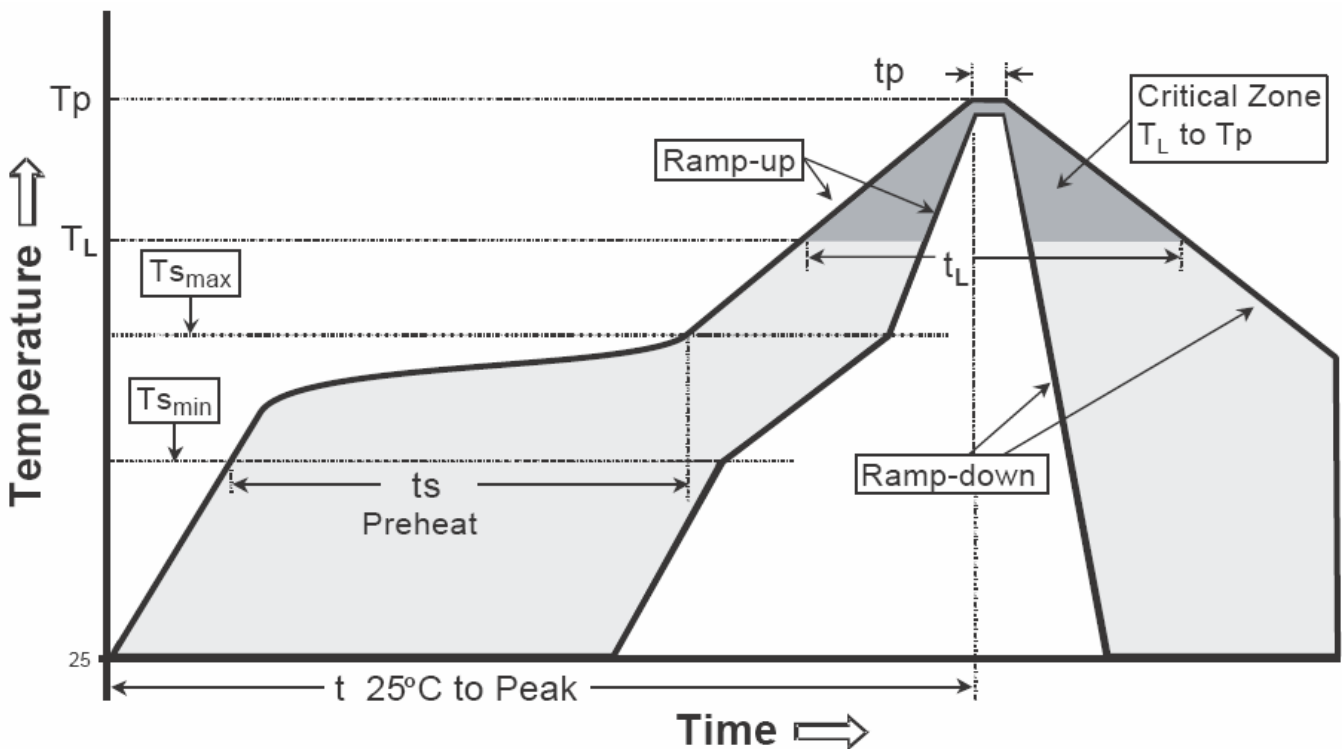


Characteristic Curves(Cont.)



Recommended wave soldering condition

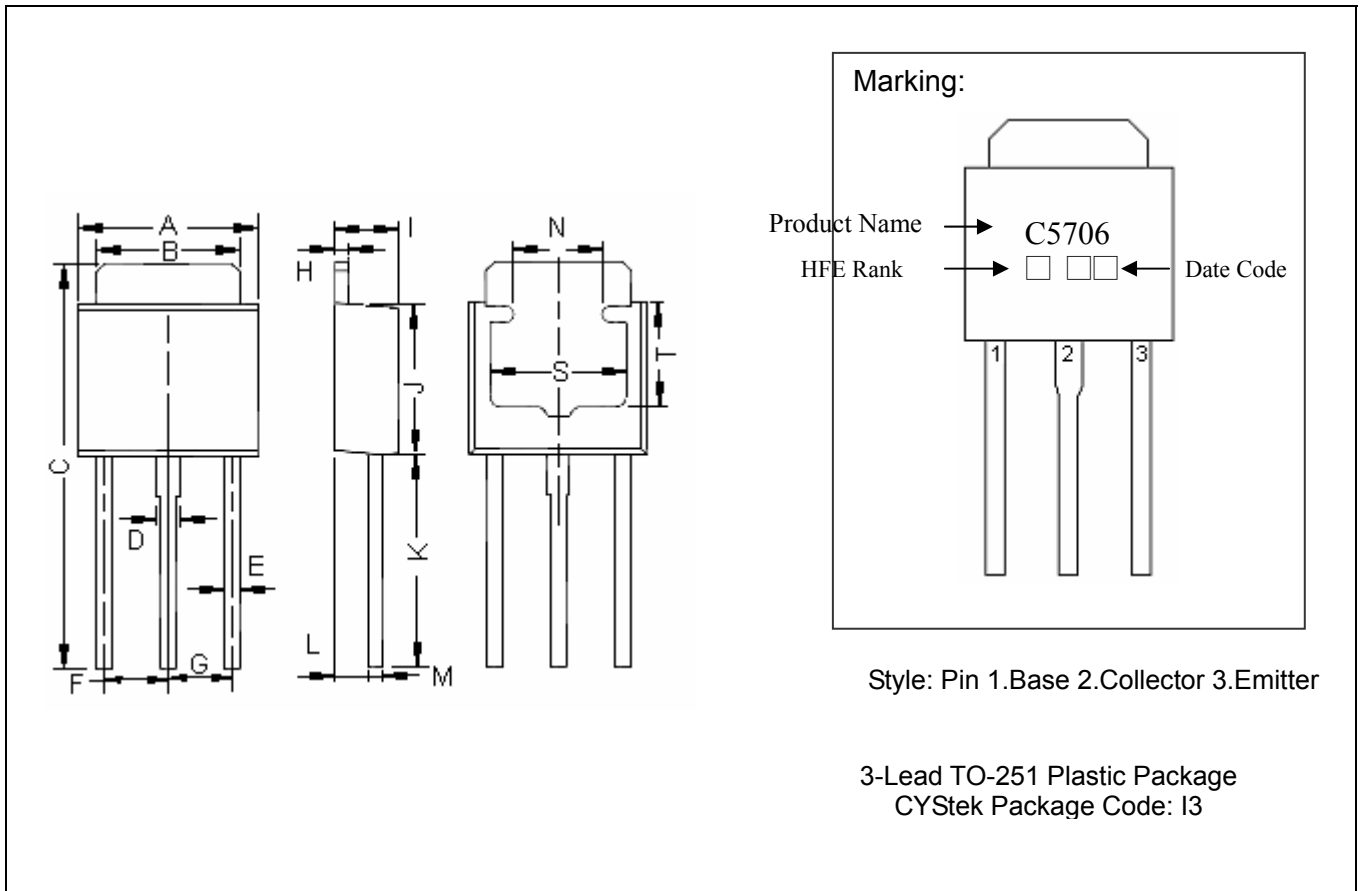
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (Tl)	183°C	217°C
- Time (tl)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

TO-251AB Dimension



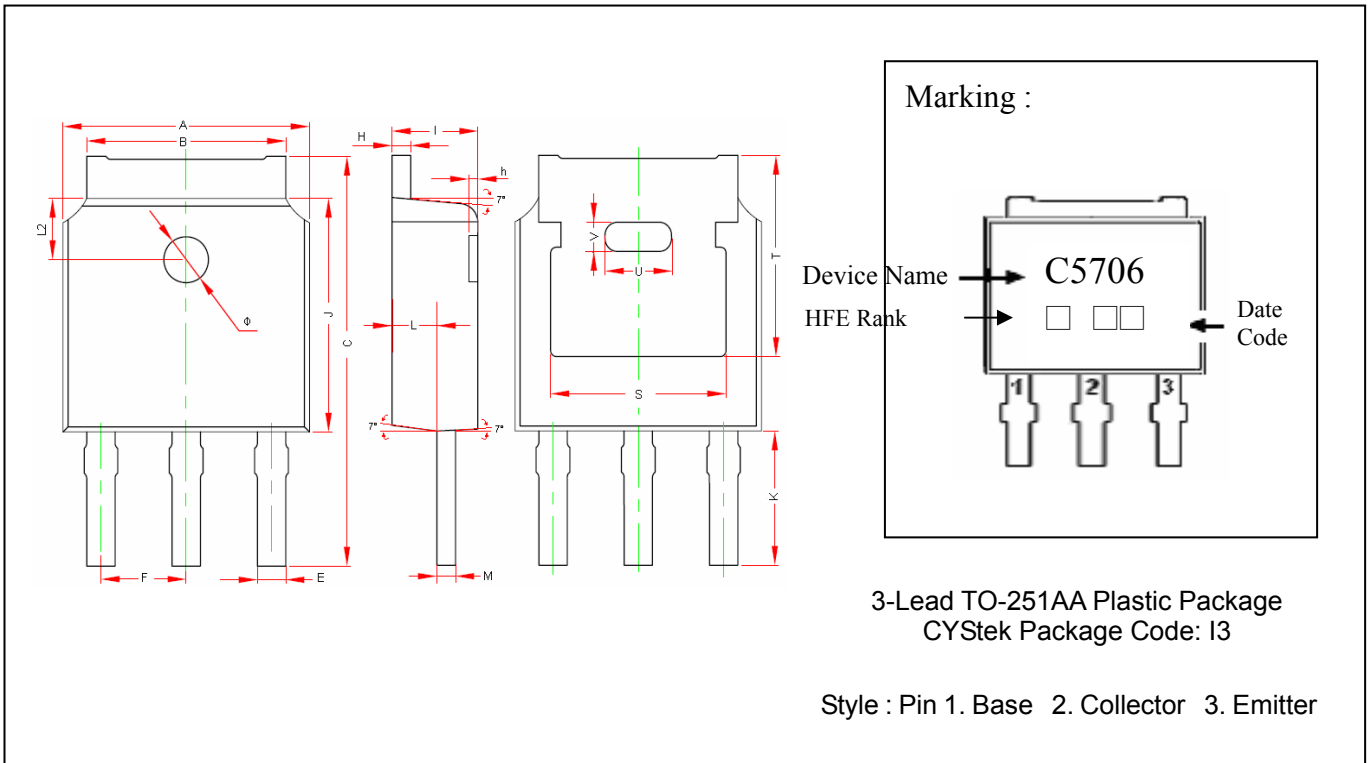
DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.250	0.262	6.350	6.650	I	0.087	0.094	2.200	2.400
B	0.205	0.213	5.200	5.400	J	0.213	0.224	5.400	5.700
C	0.571	0.587	14.500	14.900	K	0.295	0.311	7.500	7.900
D	0.028	0.035	0.700	0.900	L	0.042	0.054	1.050	1.350
E	0.020	0.028	0.500	0.700	M	0.017	0.023	0.430	0.580
F	0.091 TYP		2.300 TYP		N	0.118 REF		3.000 REF	
G	0.091 TYP		2.300 TYP		S	0.197 REF		5.000 REF	
H	0.017	0.023	0.430	0.580	T	0.150 REF		3.800 REF	

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

TO-251AA Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.256	0.264	6.500	6.700	K	0.138	REF	3.500	REF
B	0.201	0.215	5.100	5.460	L	0.036	0.046	0.910	1.110
C	0.409	0.433	10.400	11.000	L2	0.063	REF	1.600	REF
E	0.026	0.034	0.660	0.860	M	0.018	0.023	0.460	0.580
F	0.086	0.094	2.186	2.386	S	0.190	REF	4.830	REF
H	0.018	0.023	0.460	0.580	T	0.211	REF	5.350	REF
h	0.000	0.012	0.000	0.300	U	0.070	REF	1.780	REF
I	0.087	0.094	2.200	2.400	V	0.030	REF	0.760	REF
J	0.236	0.244	6.000	6.200	Φ	0.043	0.051	1.100	1.300

Notes: 1.Controlling dimension: inch.
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Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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